

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Surface-mounted package
- ☒ Low gate charge
- ☒ Advanced trench cell design

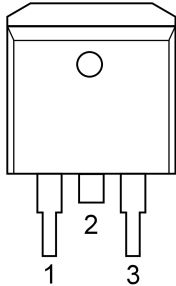
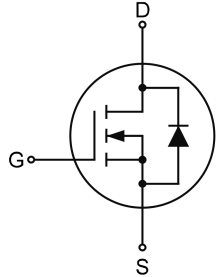
1.2 Applications

- ☒ DC/DC Converter
- ☒ BMS
- ☒ High power inverter system

1.3 Quick reference

- ☒ $BV \geq 100\text{ V}$
- ☒ $P_D \leq 178\text{ W}$
- ☒ $I_D \leq 120\text{ A}$
- ☒ $R_{DS(ON)} \leq 4.2\text{ m}\Omega @ V_{GS} = 10\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO-263	
2	Drain(D)		
3	Source(S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	Drain-Source Voltage	T _C =25℃	100	-	V
V _{GS}	Gate-Source Voltage	T _C =25℃	-	±20	V
I _D	Drain Current (DC)	T _C =25℃, V _{GS} =10 V	-	120	A
		T _C =100℃, V _{GS} =10 V	-	75	A
I _{DM} **	Drain Current (Pulsed)	T _C =25℃, V _{GS} =10 V	-	480	A
P _D	Drain power dissipation	T _C =25℃	-	178	W
I _S	Continuous-Source Current	T _C =25℃	-	120	A
E _{AS}	Single Pulsed Avalanche Energy	V _{DD} =50 V, L=0.5 mH	-	450	mJ
T _J , T _{stg}	Operating Junction and Storage Temperature Range		-55	150	℃
R _{θJA}	Thermal Resistance, Junction to Ambient		-	53	℃/W
R _{θJC}	Thermal Resistance, Junction to Case		-	0.7	

Notes:

- * Surface mounted on 1 in² pad area, t ≤ 10 sec.
- ** Pulse width ≤ 300 μs, duty cycle ≤ 2%.
- *** Limited by bonding wire.

4. Marking Information

Product Name	Marking
KJ042N10DA	KJ042N10DA XXXXXX-X

5. Ordering Code

Product Name	Package	Reel size	Tape width	Quantity (pcs)
KJ042N10DA	TO-263	13"	24 mm	800

Note: KUAJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

6. Electrical Characteristics (T_A=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _{DS} =250 μA	100	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250 μA	2.4	-	3.6	V
I _{DSS}	Drain Leakage Current	V _{DS} =100 V, V _{GS} =0 V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{DS} =0 V, V _{GS} =±20 V	-	-	±100	nA
R _{DS(ON)}	On-State Resistance	V _{GS} =10 V, I _{DS} =30 A	-	3.8	4.2	mΩ
g _{FS}	Forward Transconductance	V _{GS} =5 V, I _{DS} =30 A	-	125	-	S
R _g	Gate Resistance	f=1 MHz	-	1	-	Ω
Diode Characteristics						
V _{SD}	Diode Forward Voltage	V _{GS} =0 V, I _{SD} =30 A	-	0.9	1.2	V
t _{rr}	Reverse Recovery Time	V _{DS} =50 V, I _{DS} =30 A, V _{GS} =0 V, dI _{SD} /dt=100 A/μs	-	50	-	ns
Q _{rr}	Reverse Recovery Charge		-	108	-	nC
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{DS} =50 V, V _{GS} =10 V, Frequency=1 MHz	-	4750	-	pF
C _{oss}	Output Capacitance		-	850	-	
C _{rss}	Reverse Transfer Capacitance		-	29	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =50 V, V _{GEN} =10 V, R _G =6 Ω, I _{DS} =30 A	-	63	-	ns
t _r	Turn-on Rise Time		-	70	-	
t _{d(off)}	Turn-off Delay Time		-	86	-	
t _f	Turn-off Fall Time		-	41	-	
Gate Charge Characteristics						
Q _g	Total Gate Charge	V _{DS} =50 V, V _{GS} =10 V, I _{DS} =30 A	-	81	-	nC
Q _{gs}	Gate-Source Charge		-	22	-	
Q _{gd}	Gate-Drain Charge		-	26	-	

7. Typical Characteristics

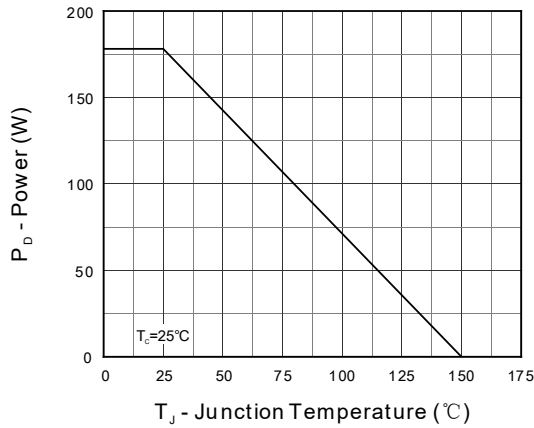


Figure 1. Power Capability

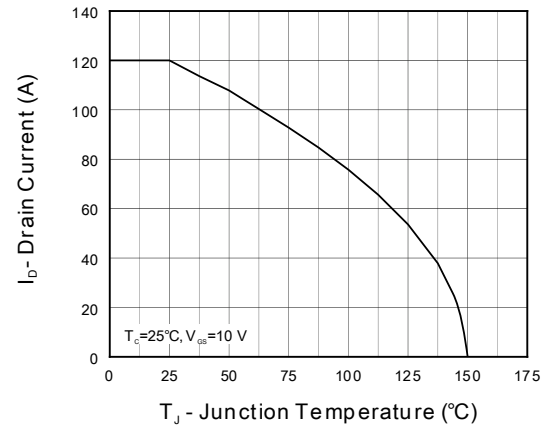


Figure 2. Current Capability

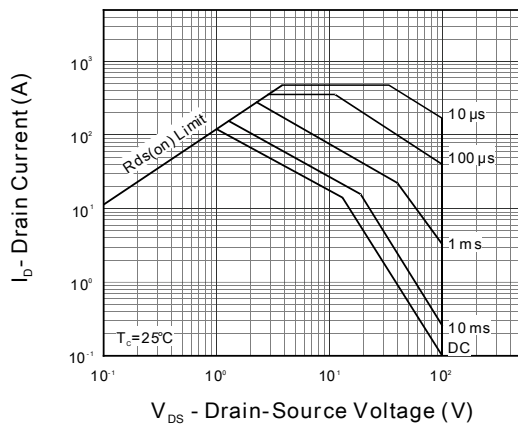


Figure 3. Safe Operation Area

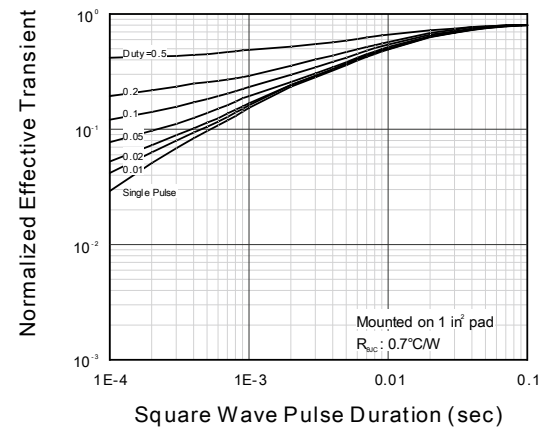


Figure 4. Transient Thermal Impedance

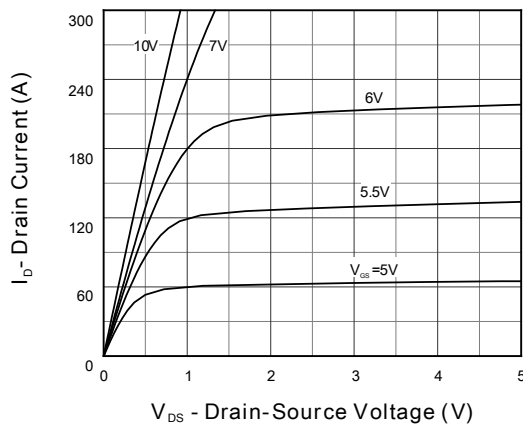


Figure 5. Output Characteristics

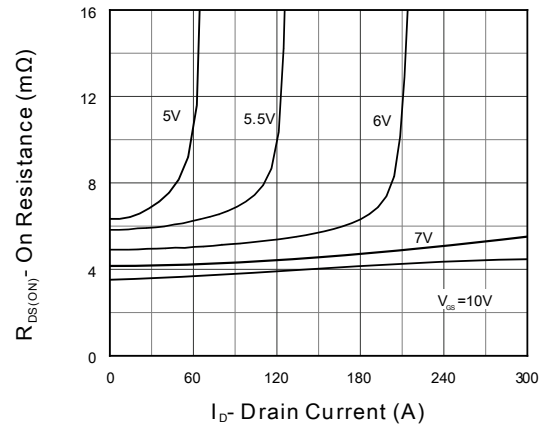


Figure 6. On Resistance

7. Typical Characteristics (Cont.)

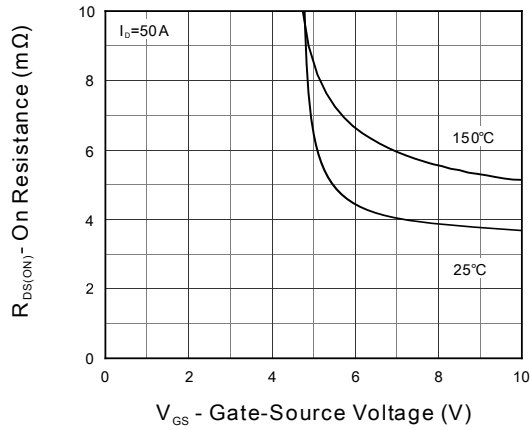


Figure 7. Transfer Characteristics

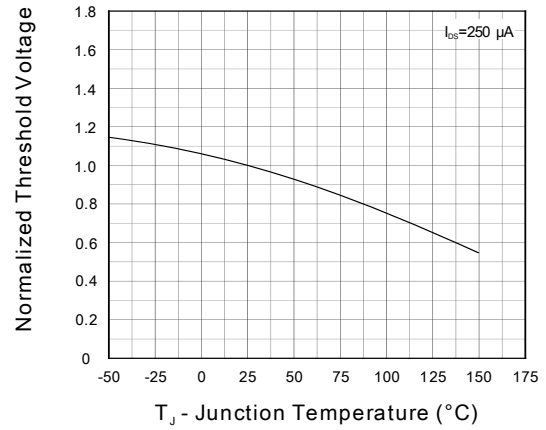


Figure 8. Normalized Threshold Voltage

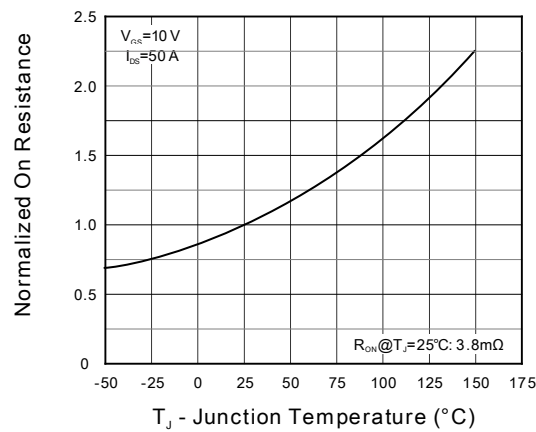


Figure 9. Normalized On Resistance

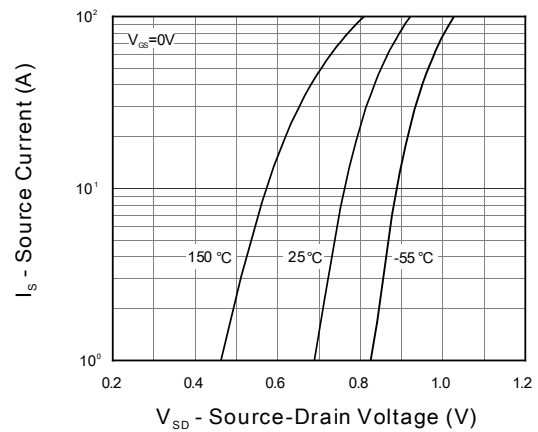


Figure 10. Diode Forward Current

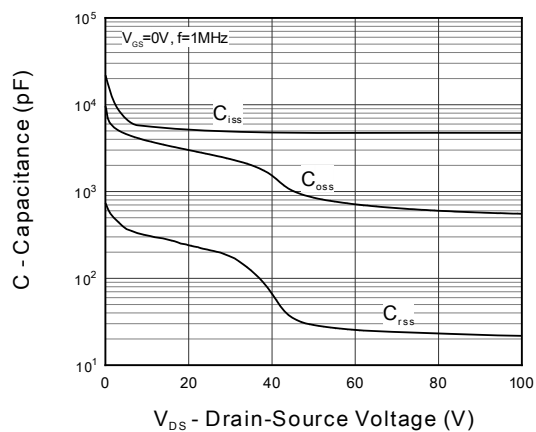


Figure 11. Capacitance

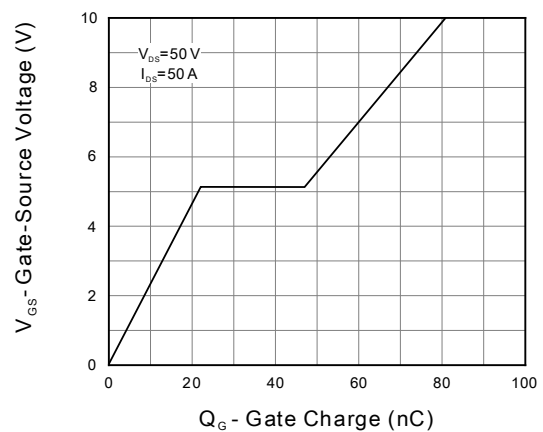
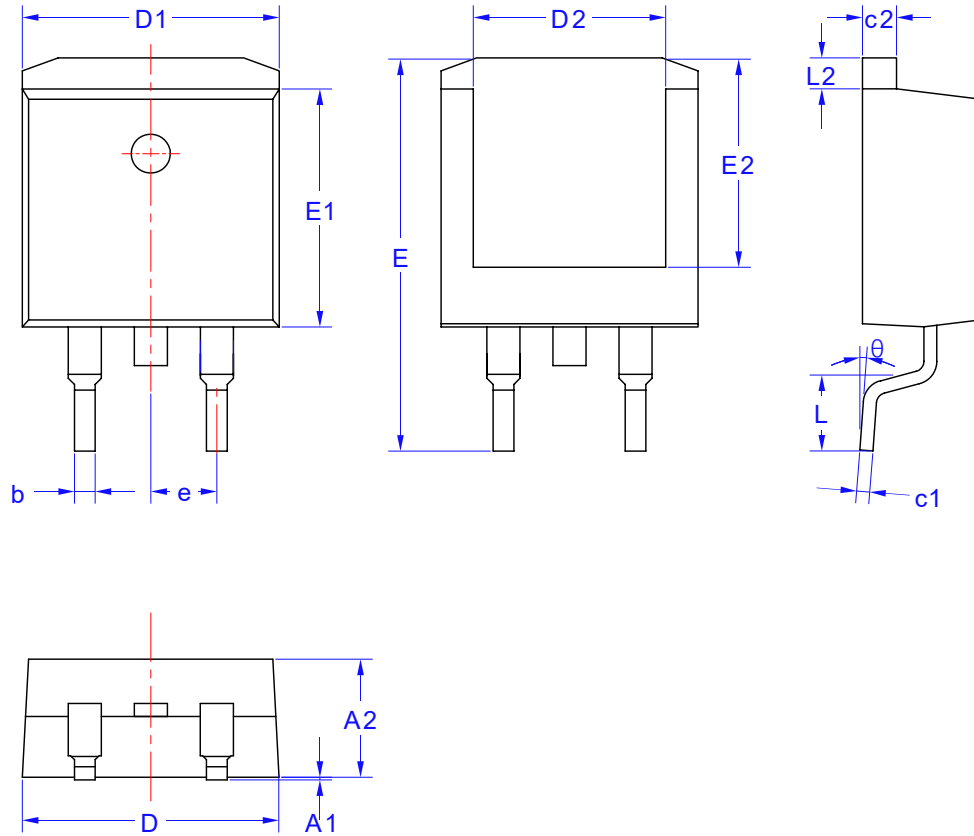


Figure 12. Gate Charge

8. Package Dimensions

TO-263 Package



Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX
A1	0.02	-	0.20
A2	4.47	4.57	4.67
b1	0.75	-	0.85
b2	1.22	-	1.32
c1	0.50	-	0.55
c2	1.30	-	1.35
D	9.78	9.88	9.98
D1		9.88 REF	

Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX
D2		7.40 REF	
E	14.90	15.10	15.30
E1	9.10	9.20	9.30
E2		8.10 REF	
e		2.54 REF	
L	2.10	2.30	2.50
L1	1.025	-	1.375
θ		0~8°	